

SANYO Semiconductors DATA SHEET

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CMOS LSI

LC717A00AR — Capacitance-Digital-Converter LSI for Electrostatic Capacitive Touch Sensors

Overview

The LC717A00AR is a high-performance, low-cost capacitance-digital-converter LSI for electrostatic capacitive touch sensor, especially focused on usability. It has 8 channels capacitance-sensor input. The built-in logic circuit can detect the state (ON/OFF) of each input and output the result. This makes it ideal for various switch applications. The calibration function is automatically performed by the built-in logic circuit during power activation or whenever there are environmental changes. In addition, since initial settings of parameters, such as gain, are configured, LC717A00AR can operate as stand-alone when the recommended switch pattern is applied.

Also, since LC717A00AR has a serial interface compatible with I²C and SPI bus, parameters can be adjusted using external devices whenever necessary. Moreover, outputs of the 8-input capacitance data can be detected and measured as 8-bit data.

Features

- Detection system: Differential capacitance detection (Mutual capacitance type)
- Input capacitance resolution: Can detect capacitance changes in the femto Farad order
- Measurement interval (8 differential inputs): 18ms (Typ) (at initial configuration),

3ms (Typ) (at minimum interval configuration)

- External components for measurement: Not required
- Current consumption: $320\mu A$ (Typ) (V_{DD} = 2.8V), $740\mu A$ (Typ) (V_{DD} = 5.5V)
- Supply voltage: 2.6V to 5.5V • Detection operations: Switch
- Packages: VCT28
- Interface: I²C * compatible bus or SPI selectable.
 - * I²C Bus is a trademark of Philips Corporation.
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Specifications

Absolute Maximum Ratings at Ta = +25°C

Parameter	Symbol	Ratings (V _{SS} = 0V)	Unit	Remarks
Supply voltage	V_{DD}	-0.3 to +6.5	٧	
Input voltage	V _{IN}	-0.3 to V _{DD} +0.3	٧	*1
Output voltage	Vout	-0.3 to V _{DD} +0.3	V	*2
Power dissipation	Pd max	160	mW	Ta = +105°C, Mounted on a substrate *3
Peak output current	lOP	±8	mA	per terminal, 50% Duty ratio *2
Total output current	IOA	±40	mA	Output total value of LSI, 25% Duty ratio
Storage temperature	Tstg	-55 to +125	°C	

^{*1)} Apply to Cin0 to 7, Cref, nRST, SCL, SDA, SA, SCK, SI, nCS, GAIN

Recommended Operating Conditions

Parameter	Symbol	Conditions	min	typ	max	Unit	Remarks
Operating supply voltage	V _{DD}		2.6		5.5	V	
Supply ripple + noise	Vpp				±20	mV	*1
Operating temperature	Topr		-40	25	105	°C	

^{*1)} Inserting a high-valued capacitor and a low-valued capacitor in parallel between V_{DD} and V_{SS} is recommended. In this case, the small-valued capacitor should be at least $0.1\mu F$, and is mounted near the LSI.

Electrical Characteristics at V_{SS} = 0V, V_{DD} = 2.6 to 5.5V, Ta = -40 to +105°C

* Unless otherwise specified, the Cdrv drive frequency is $f_{CDRV} = 143 \text{kHz}$.

* Not tested at low temperature before shipment.

Parameter	Symbol	Conditions	min	typ	max	Unit	Remarks
Capacitance detection resolution	N				8	bit	
Output noise RMS	N _{RMS}	minimum gain setting			±1.0	LSB	*1 *3
Input offset capacitance adjustment range	CoffRANGE			±8.0		pF	*1 *3
Input offset capacitance adjustment resolution	CoffRESO			8		bit	
Cin offset drift	CinDRIFT	minimum gain setting			±8	LSB	*1
Cin detection sensitivity	CinSENSE	minimum gain setting	0.04		0.12	LSB/fF	*2
Cin pin leak current	I _{Cin}	Cin = Hi-Z		±25	±500	nA	
Cin allowable parasitic input capacitance	Cin _{SUB}	Cin against V _{SS}			30	pF	*1 *3
Cdrv drive frequency	fCDRV		100	143	186	kHz	
Cdrv pin leak current	I _{CDRV}	Cdrv = Hi-Z		±25	±500	nA	
nRST minimum pulse width	^t NRST		1			μs	*1
Power-on reset time	^t POR				20	ms	*1
Power-on reset operation condition: Hold time	tPOROP		10			ms	*1
Power-on reset operation condition: Input voltage	VPOROP				0.1	٧	*1
Power-on reset operation condition: Power supply rise rate	t _{VDD}	0V to V _{DD}	1			V/ms	*1
Pin input voltage	V _{IH}	High input	0.8V _{DD}				*4 *4
	V _{IL}	Low input			0.2V _{DD}	V	*1 *4
Pin output voltage	VOH	High output (IOH = +3mA)	0.8V _{DD}			V	*5
	V _{OL}	Low output (I _{OL} = -3mA)			0.2V _{DD}	V	5

Continued to the next page.

^{*2)} Apply to Cdrv, Pout0 to 7, SDA, SO, ERROR, INTOUT

^{*3) 4-}layer glass epoxy board (40×50×0.8t mm)

Continued from the previous page.

Parameter	Symbol	Conditions	min	typ	max	Unit	Remarks
SDA pin leak current	V _{OL} I ² C	SDA Low output			0.4	V	
		$(I_{OL} = -3mA)$			0.4	V	
Pin leak current	ILEAK				±1	μΑ	*6
Current consumption	I _{DD}	When stand-alone					
		configuration and		320	390		
		non-touch		320			
		$V_{DD} = 2.8V$					*4 *2
		when stand-alone				μА	*1 *3
		configuration and			900		
		non-touch		740			
		V _{DD} = 5.5V					
	ISTBY	During Sleep process			1	μΑ	*3

^{*1)} Design-guaranteed values (not tested before shipment)

^{*2)} Measurements conducted using the test mode in the LSI

^{*3)} $Ta = +25^{\circ}C$

^{*4)} Apply to nRST, SCL, SDA, SA, SCK, SI, nCS, GAIN

^{*5)} Apply to Cdrv, Pout0 to 7, SO, ERROR, INTOUT

^{*6)} Apply to nRST, SCL, SDA, SA, SCK, SI, nCS, GAIN

$\textbf{I}^{2}\textbf{C Compatible Bus Timing Characteristics} \ at \ V_{SS} = 0, \ V_{DD} = 2.6 \ to \ 5.5 V, \ Ta = -40 \ to \ +105 ^{\circ}C$

*Not tested at low temperature before shipment

Parameter	Symbol	Pin Name	Conditions	min	typ	max	Unit	Remarks
SCL clock frequency	fSCL	SCL				400	kHz	
START condition hold time	tHD;STA	SCL		0.0				
	,	SDA		0.6			μs	
SCL clock low period	tLOW	SCL		1.3			μs	
SCL clock high period	tHIGH	SCL		0.6			μs	
Repeated START condition	tSU;STA	SCL		0.6				*1
setup time		SDA		0.6			μs	·
Data hold time	tHD;DAT	SCL		0		0.9		
		SDA		U		0.9	μs	
Data setup time	tSU;DAT	SCL		100				*1
		SDA		100			μs	ı
SDA, SCL rise/fall time	t _r / t _f	SCL				200		*1
		SDA				300	μs	1
STOP condition setup time	tSU;STO	SCL		0.0				
		SDA		0.6			μs	
STOP-to-START bus release	tBUF	SCL		1.0				*1
time		SDA	1.3		1.3		μs	^1

^{*1)} Design-guaranteed values (not tested before shipment)

SPI Bus Timing Characteristics at V_{SS} = 0, V_{DD} = 2.6 to 5.5V, T_a = -40 to +105°C

*Not tested at low temperature before shipment

Parameter	Symbol	Pin Name	Conditions	min	typ	max	Unit	Remarks	
SCK clock frequency	fSCK	SCK				5	MHz		
SCK clock Low time	tLOW	SCK		90			ns	*1	
SCK clock High time	tHIGH	SCK		90			ns	*1	
Input signal rise/fall time	t _r / t _f	nCS							
		SCK				300	ns	*1	
		SI							
nCS setup time	tSU;NCS	nCS		90			ns	*1	
	·	SCK		90			115	ı	
SCK clock setup time	tsu;sck	nCS		90			no	*1	
	·	SCK		90			ns	'	
Data setup time	tsu;sı	SCK		20			ns	*1	
		SI		20			115	'	
Data hold time	Data hold time thD;SI SCK 30			ns	*1				
		SI		30			113	'	
nCS hold time	tHD;NCS	nCS		90	.		ns	*1	
		SCK		90					
SCK clock hold time	tHD;SCK	nCS		90			ns	*1	
		SCK		90			115	'	
nCS standby pulse width	^t CPH	nCS		90			ns	*1	
Output high impedance time	tCHZ	nCS						**	
from nCS		so				80	ns	*1	
Output data determination time	t _V	SCK							
		so				80	ns	*1	
Output data hold time	tHD:SO	SCK						+4	
	, = -	SO		0			ns	*1	
Output low impedance time	tCLZ	SCK						*1	
from SCK clock		so		0			ns	1	

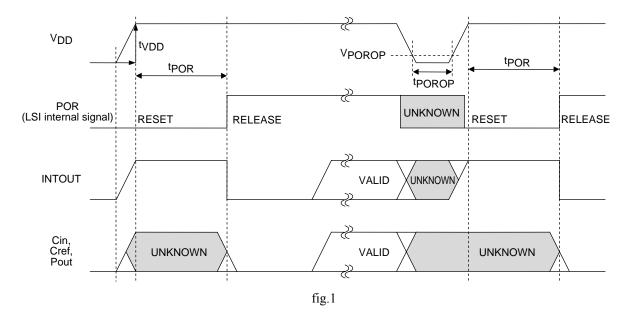
^{*1)} Design-guaranteed values (not tested before shipment)

Power-on Reset (POR)

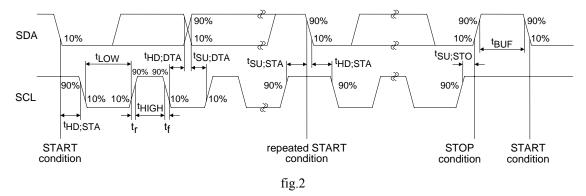
When power is turned on, power-on reset is enabled inside the LSI and its state is released after a certain power-on reset time, tpOR. Power-on reset operation condition: Power supply rise rate tVDD must be at least 1V/ms.

Since INTOUT pin changes from "High" to "Low" at the same time as the released of power-on reset state, it is possible to verify the tpor externally.

During power-on reset state, Cin, Cref and Pout are unknown.



I²C Compatible Bus Data Timing



I²C Compatible Bus Communication Formats

• Write format (data can be written into sequentially incremented addresses)

START	Slave Address	Write=L	ACK	Register Address (N)	ACK	Data written to Register Address (N)	ACK	Data written to Register Address (N+1)	ACK	STOP
			Slave		Slave		Slave		Slave	
					fig.3					

• Read format (data can be read from sequentially incremented addresses)

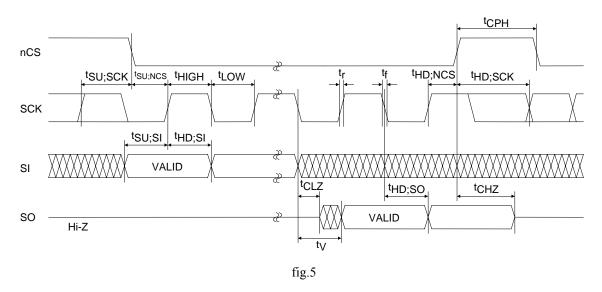
START	Slave Address	Write=L	ACK	Register Address (N)	ACK				
			Slave		Slave				
RESTART	Slave Address	Read=H	ACK	Data read from Register Address (N)	ACK	Data read from Register Address (N+1)	ACK	Data read from Register Address (N+2)	NACK
			Slave		Maste		Maste	r	Master
				1	fig 4				

I²C Compatible Bus Slave Address

Selection of two kinds of addresses is possible through the SA terminal.

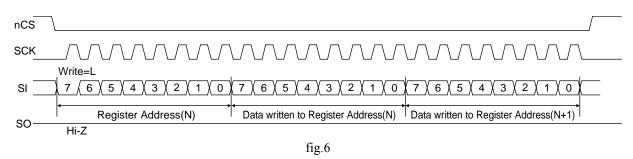
SA pin input	7bit Slave Address	Binary Notation	8bit Slave Address	
Low	0x16 00101100b (Write)		0x2C	
		00101101b (Read)	0x2D	
High	0x17	00101110b (Write)	0x2E	
		00101111b (Read)	0x2F	

SPI Data Timing (SPI Mode 0 / Mode 3)

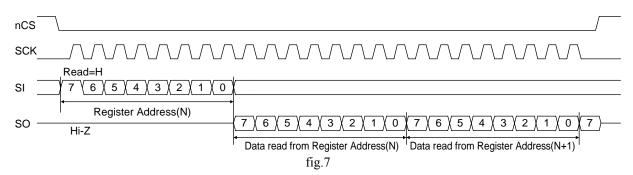


SPI Communication Formats (Example of Mode 0)

• Write format (data can be written into sequentially incremented addresses while holding nCS = L)



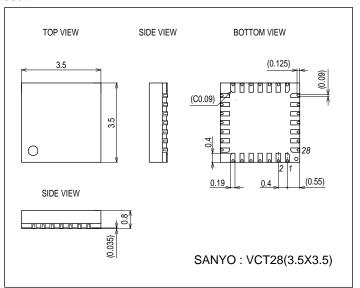
• Read format (data can be read from sequentially incremented addresses while holding nCS = L)



Package Dimensions [LC717A00AR]

unit: mm (typ)

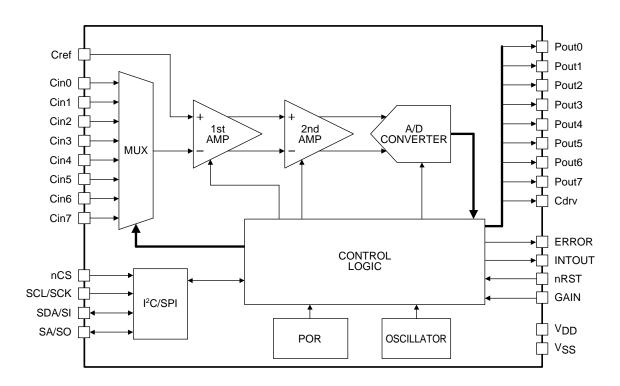
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Pin Assignment

Pin No.	Pin Name	Pin No.	Pin Name
1	Cin0	15	Pout4
2	Cin1	16	Pout5
3	Cin2	17	Pout6
4	Cin3	18	Pout7
5	V_{DD}	19	Cref
6	V _{SS}	20	ERROR
7	Cin4	21	Cdrv
8	Cin5	22	INTOUT
9	Cin6	23	GAIN
10	Cin7	24	SCL/SCK
11	Pout0	25	SDA/SI
12	Pout1	26	SA/SO
13	Pout2	27	nCS
14	Pout3	28	nRST

Block Diagram



LC717A00AR is capacitance-digital-converter LSI capable of detecting changes in capacitance in the femto Farad order. It consists of an oscillation circuit that generates the system clock, a power-on reset circuit that resets the system when the power is turned on, a multiplexer that selects the input channels, a two-stage amplifier that detects the changes in the capacitance and outputs analog-amplitude values, a A/D converter that converts the analog-amplitude values into digital data, and a control logic that controls the entire chip. Also, it has an I²C compatible bus or SPI that enables serial communication with external devices as necessary.

Pin Functions

Pin Name	I/O	Pin Functions	Pin Type
Cin0	I/O	Capacitance sensor input	Λ
Cin1	I/O	Capacitance sensor input	V _{DD} ^A
Cin2	I/O	Capacitance sensor input	AMP
Cin3	I/O	Capacitance sensor input	$\overline{}$
Cin4	I/O	Capacitance sensor input	
Cin5	I/O	Capacitance sensor input	
Cin6	I/O	Capacitance sensor input	↑
Cin7	I/O	Capacitance sensor input	V _{SS} //
Cref	I/O	Reference capacitance input	Buffer
Pout0	0	Cin0 judgment result output	
Pout1	0	Cin1 judgment result output	
Pout2	0	Cin2 judgment result output	│ V _{DD} ☆
Pout3	0	Cin3 judgment result output	
Pout4	0	Cin4 judgment result output	↑
Pout5	0	Cin5 judgment result output	1
Pout6	0	Cin6 judgment result output	Buffer
Pout7	0	Cin7 judgment result output	†
ERROR	0	Error occurrence status output	- Vaa
Cdrv	0	Output for capacitance sensors drive	Vss "
INTOUT	0	Interrupt output	
SCL/SCK	I	Clock input (I ² C) / Clock input (SPI)	V _{DD} ^Δ
GAIN	ı	Selection pin of the initial value of gain of the 2nd-amplifier	R
nCS	I	Interface selection / Chip select inverting input (SPI)	
nRST	I	External reset signal inverting input	V _{SS} m
SDA/SI	1/0	Data input and output (I ² C) / Data input (SPI)	V _{DD} A R R V _{SS} m
SA/SO	I/O	Slave address selection (I ² C) / Data output (SPI)	V _{DD} A R W W Buffer
V _{DD}		Power supply (2.6V to 5.5V) *1	
V _{SS}		Ground (Earth) *1 *2	

^{*1)} Inserting a high-valued capacitor and a low-valued capacitor in parallel between V_{DD} and V_{SS} is recommended. In this case, the small-valued capacitor should be at least 0.1μF, and is mounted near the LSI.

^{*2)} When VSS terminal is not grounded in battery-powered mobile equipment, detection sensitivity may be degraded.

Details of Pin Functions

●Cin0 to Cin7

These are the capacitance-sensor-input pins. These pins are used by connecting them to the touch switch pattern. Cin and the Cdrv wire patterns should be close to each other. By doing so, Cdrv and Cin patterns are capacitively coupled. Therefore, LSI can detect capacitance change near each pattern as 8bit digital data.

However, if the shape of each pattern or the capacitively coupled value of Cdrv is not appropriate, it may not be able to detect the capacitance change correctly.

In this LSI, there is a two-stage amplifier that detects the changes in the capacitance and outputs analog-amplitude values. Cin0 to Cin7 are connected to the inverting input of the 1st amplifier in the LSI.

During measurement process, channels other than the one being measured are all in "Low" condition.

Leave the unused terminals open.

Cref

It is the reference-capacitance-input pin. It is used by connecting to the wire pattern like Cin pins or is used by connecting any capacitance between this pin and Cdrv pin.

In this LSI, there is a two-stage amplifier that detects the changes in the capacitance and outputs analog-amplitude values. Cref is connected to the non-inverting input of the 1st amplifier in the LSI.

Due to the parasitic capacitance generated in the wire connections of Cin pins and their patterns, as well as the one generated between the wire patterns of Cin and Cdrv pins, Cref may not detect capacitance change of each Cin pin accurately. In this case, connect an appropriate capacitance between Cref and Cdrv to detect capacitance change accurately.

However, if the difference between the parasitic capacitance of each Cin pin is extremely large, it may not detect capacitance change in each Cin pin correctly.

Pout0 to Pout7

These are the detection-result-output pins. The capacitance detection results of Cin0 to Cin7 are compared with the threshold of the LSI. The pin outputs a "High" or a "Low" depending on the result.

ERROR

It is the error-occurrence-status-output pin.

It outputs "Low" during normal operation. If there is a calibration error or a system error, it outputs "High" to indicate that an error occurred.

•Cdrv

It is the output pin for capacitance sensors drive. It outputs the pulse voltage which is needed to detect capacitance at Cin0 to Cin7.

Cdrv and Cin wire patterns should be close to each other so that they are capacitively coupled.

•INTOUT

It is the interrupt-output pin. It outputs "High" when a measurement process is completed.

Connect to a main microcomputer if necessary, and use as interrupt signal.

Leave the terminal open if not in used.

•SCL/SCK

Clock input (I²C) / Clock input (SPI)

It is the clock input pin of the I²C compatible bus or the SPI depending on the mode of operation.

If interface is not to be used, fix the pin to "High". However, even if interface is not to be used, providing a communication terminal on board is still recommended.

•GAIN

In this LSI, there is a two-stage amplifier that detects the changes in the capacitance and outputs analog-amplitude values. It is the selection pin of the initial value of gain of the 2nd amplifier.

Even if this LSI is used alone, gain setting can still be selected through this terminal. At initialization of the LSI, it is set to 7-times higher than the minimum setting when GAIN pin is "Low", and is set to 14-times higher than the minimum setting when GAIN pin is "High".

nCS

Interface selection / Chip-select-inverting input (SPI)

Selection of I^2C compatible bus mode or SPI mode is through this terminal. After initialization, the LSI is automatically in I^2C compatible bus mode. To continually use I^2C compatible bus mode, fix nCS pin to "High". To switch to SPI mode after LSI initialization, change the nCS input "High" \rightarrow "Low". The nCS pin is used as the chipselect-inverting input pin of SPI, and SPI mode is kept until LSI is again initialized. If interface is not to be used, fix the pin to "High".

nRST

It is the external-reset-signal-inverting-input pin. When nRST pin is "Low", LSI is in the reset state. Each pin (Cin0 to 7, Cref, Pout,0 to 7, ERROR) is "Hi-Z" during reset state.

•SDA/SI

Data input and output (I^2C) / Data input (SPI)

It is the data input and output pin of the I²C compatible bus or the data input pin of the SPI depending on the mode of operation.

If interface is not to be used, fix the pin to "High". However, even if interface is not to be used, providing a communication terminal on board is still recommended.

•SA/SO

Slave address selection (I²C) / Data output (SPI)

It is the slave address selection pin of the I²C compatible bus or the data output pin of the SPI depending on the mode of operation.

If interface is not to be used, fix the pin to "High". However, even if interface is not to be used, providing a communication terminal on board is still recommended.

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